MOSPEC

S60D90 Thru S60D100

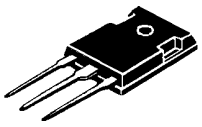
SCHOTTKY BARRIER RECTIFIERS

60 AMPERES
90-100 VOLTS

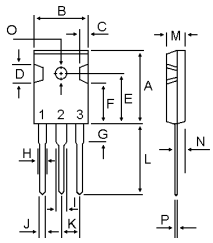
Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

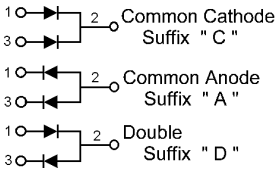
- ＊Low Forward Voltage.
- ＊Low Switching noise.
- ＊High Current Capacity
- ＊Guarantee Reverse Avalanche.
- ＊Guard-Ring for Stress Protection.
- ＊Low Power Loss & High efficiency.
- ＊150℃ Operating Junction Temperature
- ＊Low Stored Charge Majority Carrier Conduction.
- ＊Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- ＊ESD: 4KV(Min.) Human-Body Model
- ＊*In compliance with EU RoHs 2002/95/EC directives*



TO-3P



DIM	MILLIMETERS	
	MIN	MAX
A	20.63	22.38
B	15.38	16.20
C	1.90	2.70
D	5.10	6.10
E	14.81	15.22
F	11.72	12.84
G	4.20	4.50
H	1.82	2.46
I	2.92	3.23
J	0.89	1.53
K	5.26	5.66
L	18.50	21.50
M	4.68	5.36
N	2.40	2.80
O	3.25	3.65
P	0.55	0.70



MAXIMUM RATINGS

Characteristic	Symbol	S60D90	S60D100	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	90	100	V
RMS Reverse Voltage	$V_{R(RMS)}$	63	70	V
Average Rectifier Forward Current Per diodes Total Device (Rated V_R),T_C=100℃	$I_{F(AV)}$	30 60		A
Peak Repetitive Forward Current (Rate V_R, Square Wave, 20kHz)	I_{FM}	60		A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I_{FSM}	450		A
Operating and Storage Junction Temperature Range	T_J , T_{STG}	-65 to +150		℃

THERMAL RESISTANCES

Typical Thermal Resistance junction to case	$R_{\theta j\text{-}c}$	1.5	℃/w

ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	S60D90	S60D100	Unit
Maximum Instantaneous Forward Voltage (I_F =30 Amp T_C = 25℃) (I_F =30 Amp T_C = 100℃)	V_F	0.95 0.78		V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25℃) (Rated DC Voltage, T_C = 125℃)	I_R	3.0 60		mA

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FIG-1 FORWARD CURRENT DERATING CURVE

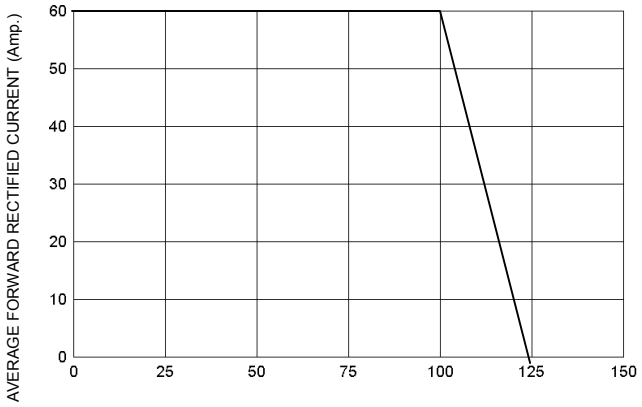


FIG-2 TYPICAL FORWARD CHARACTERISITICS

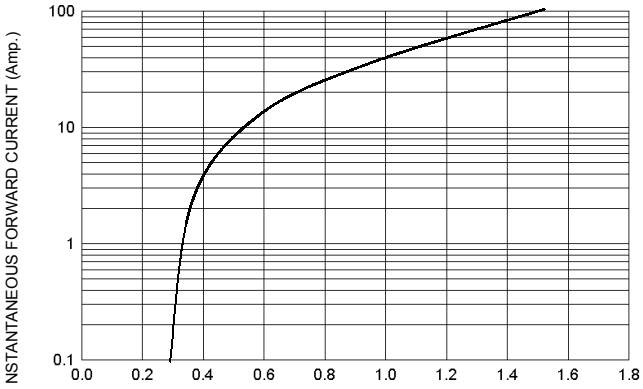


FIG-3 TYPICAL REVERSE CHARACTERISTICS

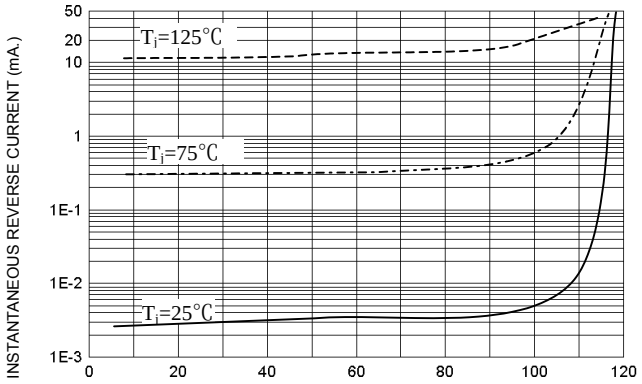


FIG-4 TYPICAL JUNCTION CAPACITANCE

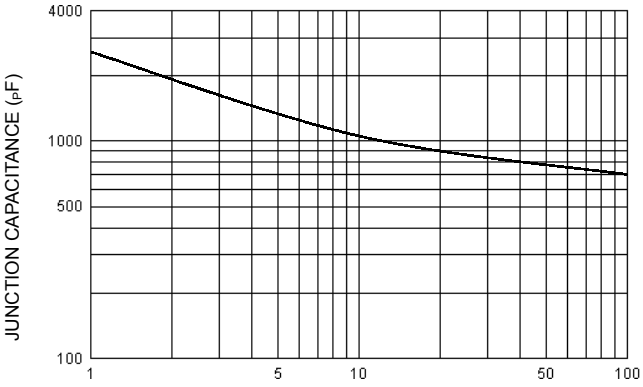
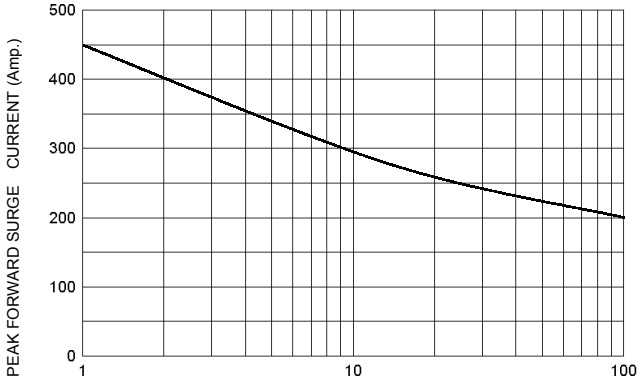


FIG-5 PEAK FORWARD SURGE CURRENT



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